NSN 5961-01-029-6114

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-029-6114 **Inclosure Material:** Metal **Overall Length:** Between 0.385 inches and 0.395 inches **Overall Height:** Between 0.145 inches and 0.155 inches Overall Width: Between 0.305 inches and 0.315 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 breakdown voltage, collector-to-base, emitter open and 75.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 1.00 amperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 pin **Specification Data:** 80131-release6265 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No